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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO
10/681,781	10/08/2003	Sergey A. Kostylev	2024.42	6696
75	90 11/05/2004		EXAMINER	
Philip H. Schlazer			JACKSON JR, JEROME	
Energy Conversion Devices, Inc. 2956 Waterview Drive			ART UNIT	PAPER NUMBER
Rochester Hills	. =		2815	
			DATE MAILED: 11/05/2004	4

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)	
	10/681,781	KOSTYLEV ET AL.	
Office Action Summary	Examiner	Art Unit	
	Jerome Jackson Jr.	2815	
The MAILING DATE of this communication app Period for Reply	ears on the cover sheet with the	correspondence address	
A SHORTENED STATUTORY PERIOD FOR REPL' THE MAILING DATE OF THIS COMMUNICATION. - Extensions of time may be available under the provisions of 37 CFR 1.1: after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a reply - If NO period for reply is specified above, the maximum statutory period v - Failure to reply within the set or extended period for reply will, by statute Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be to within the statutory minimum of thirty (30) de will apply and will expire SIX (6) MONTHS front, cause the application to become ABANDON	timely filed ays will be considered timely. m the mailing date of this communication IED (35 U.S.C. § 133).	
Status			
1) Responsive to communication(s) filed on 2a) This action is FINAL . 2b) This 3) Since this application is in condition for allowar closed in accordance with the practice under E	action is non-final. nce except for formal matters, p		
Disposition of Claims			
4) ☐ Claim(s) 1-20 is/are pending in the application. 4a) Of the above claim(s) is/are withdray 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 1-20 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction and/o	wn from consideration.		
Application Papers		•	
9)☐ The specification is objected to by the Examine 10)☒ The drawing(s) filed on <u>08 October 2003</u> is/are: Applicant may not request that any objection to the Replacement drawing sheet(s) including the correct 11)☐ The oath or declaration is objected to by the Ex	a) \square accepted or b) \square objected drawing(s) be held in abeyance. So ion is required if the drawing(s) is o	ee 37 CFR 1.85(a). bjected to. See 37 CFR 1.121(d).
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority documents 2. Certified copies of the priority documents 3. Copies of the certified copies of the priority application from the International Bureau * See the attached detailed Office action for a list	s have been received. s have been received in Applica rity documents have been receiv u (PCT Rule 17.2(a)).	tion Noved in this National Stage	
Attachment(s)			
Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08) Paper No(s)/Mail Date	4) Interview Summar Paper No(s)/Mail [5] Notice of Informal 6) Other:		

Application/Control Number: 10/681,781

Art Unit: 2815

The disclosure is objected to because of the following informalities: on page 7 (and perhaps the figures) there is confusion between 110 and 120 as to which is the substrate and which is the conductor. On page 14 line 20 "120" should be –130--.

Appropriate correction is required.

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.

Claims 1,4-6,9,10,11,12,14-17,19 and 20 are rejected under 35 U.S.C. 102(b) as being anticipated by Wolstenholme '059 (W).

W teaches in figure 5 a programmable resistance material 55, threshold switching material comprising silicon layers 10, 20, and 24, and a first layer of dielectric 45 between the programmable material and threshold switching material. Note that the p-n junction diode material can be labeled a threshold switching material as it switches or conducts a large current upon reaching a threshold voltage bias as is well known in the art. Accordingly claim 1 is rejected. Claim 4 is rejected as 80 comprises a second layer of dielectric material and the programmable resistance material is between the first and second dielectric materials. Claims 5 and 6 are rejected as layer 55 is a chalcogenide phase change material. Claims 9 and 10 are rejected as the dielectric 45

Art Unit: 2815

is silicon nitride. Claims 11,12,14-17,19 and 20 are rejected as above noting that "over" or "under" is relative and the chalcogenide material inherently posseses S-type currentvoltage properties.

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 7,13,18 are rejected under 35 U.S.C. 103(a) as being unpatentable over Wolstenholme in view of Parkinson '338.

Parkinson suggests access devices of phase change material such as chalcogenides. It would have been prima facie obvious to have practiced a device as W with access devices of phase change materials rather than silicon diode materials to decrease the memory cell size (column 1 of '338). Claims 7, 13 and 18 are obvious structure.

Claim 8 is rejected under 35 U.S.C. 103(a) as being unpatentable over W in view of Kozicki 914.

Kozicki teaches a high resistance barrier or "stabilizing" layer 155 or 255 of silicon dioxide between an electrode and phase change material (column 7 lines 12-18). It would have been obvious to have practiced a similar layer in W to increase the write voltage (column 8) or limit diffusion of unwanted materials. The thickness of the barrier layer is considered obvious at 1-100nm from column 16 line 10. Claim 8 is obvious structure.

Art Unit: 2815

Claims 1-9,11-20 are rejected under 35 U.S.C. 102(e) as being anticipated by Kostylev '730

The applied reference has a common assignee and inventor with the instant application. Based upon the earlier effective U.S. filing date of the reference, it constitutes prior art under 35 U.S.C. 102(e). This rejection under 35 U.S.C. 102(e) might be overcome either by a showing under 37 CFR 1.132 that any invention disclosed but not claimed in the reference was derived from the inventor of this application and is thus not the invention "by another," or by an appropriate showing under 37 CFR 1.131.

Kostylev teaches layers of chalcogenide (i.e. programmable resistance material and threshold switching material) between layers of dielectric (oxides, nitrides, etc. of "stabilizing" material). See paragraph 45 and figure 7. Claims 1-9 are broad and undistinguishing over '730.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Jerome Jackson Jr. whose telephone number is 571 272 1730. The examiner can normally be reached on t-th 9-5.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached on 571 272 1664. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Application/Control Number: 10/681,781

Art Unit: 2815

Page 5

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

jj

JEROME JACKSON PRIMARY EXAMINER